VTS Process Photodiodes

VTS__80, 82, 85

PRODUCT DESCRIPTION

This series of planar, P on N, large area silicon photodiodes is characterized for use in the photovoltaic (unbiased) mode. Their excellent speed and broadband sensitivity makes them ideal for detecting light from a variety of sources such as LEDs, IREDs, flashtubes, incandescent lamps, lasers, etc. Improved shunt resistance minimizes amplifier offset and drift in high gain systems. The solderable contact system on these photodiodes provides a cost effective design solution for many applications.

ABSOLUTE MAXIMUM RATINGS

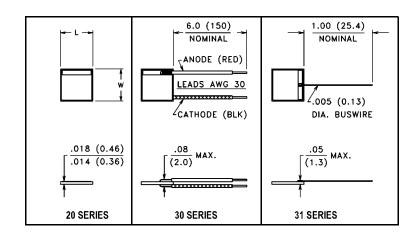
Storage Temperature:

-40°C to 150°C Series 20, 31 -40°C to 105°C Series 30 Operating Temperature:

> -40°C to 125°C Series 20, 31 -40°C to 105°C Series 30

Reverse Voltage: 6.0 Volts

PACKAGE DIMENSIONS inch (mm)



CASE 44A ANODE (ACTIVE) SURFACE SHOWN CATHODE IS BACKSIDE

DIMENSIONS	VTS80	VTS82	VTS85
L	.800 (20.32)	.400 (10.16)	.200 (5.08)
W	.800 (20.32)	.400 (0.16)	.200 (5.08)
ACTIVE AREA	.607 ² (392 ²)	.144 ² (93 ²)	.032 ² (21 ²)

ELECTRO-OPTICAL CHARACTERISTICS @ 25°C (See also VTS curves, page 67)

SYMBOL CHARACTERISTIC	CHADACTEDISTIC	TEST CONDITIONS	VTS80		VTS82		VTS85			UNITS		
	CHARACTERISTIC		Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	UNITS
I_{SC}	Short Circuit Current	H = 1000 lux, 2850 K	2.30	3.00		0.55	0.69		0.13	0.16		mA
TC I _{SC}	I _{SC} Temperature Coefficient	H = 1000 Lux, 2850 K		0.20			0.20			0.20		%/°C
I_{D}	Dark Current	H = 0, VR = 100 mV		0.2	1.0		0.05	0.2		0.02	0.1	μA
TC I _D	ID Temp. Coefficient	H = 0, VR = 100 mV		+11			+11			+11		%/°C
R _{SH}	Shunt Resistance	H = 0, VR = 10 mV		0.3			1.2			3.0		MΩ
C_{J}	Junction Capacitance	H = 0, V = 0 V, 1 MHz		7.5			1.75			0.50		nF
S_R	Sensitivity	@ 400 nm	.18	0.20		0.18	0.20		0.18	0.20		A/W
Re	Responsivity	400 nm, 0.18 A/W		0.70			0.16			0.04		A/(W/cm ²)
TC V _{OC}	Sensitivity @ Peak	925 nm		0.60			0.60			0.60		A/W
t _R /t _F	Response Time @ 1 kΩ Load	VR = 1 V, 830 nm		13			3.4			1.2		µsec
V _{OC}	Open Circuit Voltage	H = 1000 Lux, 2850 K	0.25	0.45		0.25	0.45		0.25	0.45		Volts
TC V _{OC}	V _{OC} Temperature Coefficient	H = 1000 Lux, 2850 K		-2.6			-2.6			-2.6		mV/°C